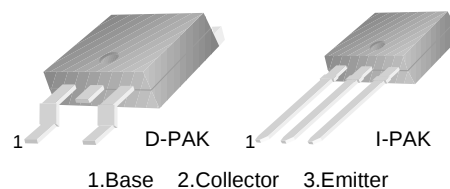


KSH210

KSH210

D-PAK for Surface Mount Applications

- High DC Current Gain
- Low Collector Emitter Saturation Voltage
- Lead Formed for Surface Mount Applications (No Suffix)
- Straight Lead (I-PAK, " - I " Suffix)



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	- 40	V
V_{CEO}	Collector-Emitter Voltage	- 25	V
V_{EBO}	Emitter-Base Voltage	- 8	V
I_C	Collector Current (DC)	- 5	A
I_{CP}	Collector Peak Current (Pulse)	- 10	A
I_B	Base Current	- 1	A
P_C	Collector Dissipation ($T_C = 25^{\circ}\text{C}$)	12.5	W
	Collector Dissipation ($T_a = 25^{\circ}\text{C}$)	1.4	W
T_J	Junction Temperature	150	$^{\circ}\text{C}$
T_{STG}	Storage Temperature	- 65 ~ 150	$^{\circ}\text{C}$

Electrical Characteristics $T_C=25^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
$V_{CEO(sus)}$	* Collector-Emitter Sustaining Voltage	$I_C = - 10\text{mA}$, $I_B = 0$	-25		V
I_{CBO}	Collector Cut-off Current	$V_{CB} = - 40\text{V}$, $I_E = 0$		-100	nA
I_{EBO}	Emitter Cut-off Current	$V_{EB} = - 8\text{V}$, $I_C = 0$		-100	nA
h_{FE}	* DC Current Gain	$V_{CE} = - 1\text{V}$, $I_C = - 500\text{mA}$ $V_{CE} = - 1\text{V}$, $I_C = - 2\text{A}$ $V_{CE} = - 2\text{V}$, $I_C = - 5\text{A}$	70 45 10	180	
$V_{CE(sat)}$	* Collector-Emitter Saturation Voltage	$I_C = - 500\text{mA}$, $I_B = - 50\text{mA}$ $I_C = - 2\text{A}$, $I_B = - 200\text{mA}$ $I_C = - 5\text{A}$, $I_B = - 1\text{A}$		-0.3 -0.75 -1.8	V V V
$V_{BE(sat)}$	* Base-Emitter Saturation Voltage	$I_C = - 5\text{A}$, $I_B = - 1\text{A}$		-2.5	V
$V_{BE(on)}$	* Base-Emitter On Voltage	$V_{CE} = - 1\text{V}$, $I_C = - 2\text{A}$		-1.6	V
f_T	Current Gain Bandwidth Product	$V_{CE} = - 10\text{V}$, $I_C = - 100\text{mA}$	65		MHz
C_{ob}	Output Capacitance	$V_{CB} = - 10\text{V}$, $I_E = 0$, $f = 0.1\text{MHz}$		120	pF

* Pulse Test: $PW \leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

Typical Characteristics

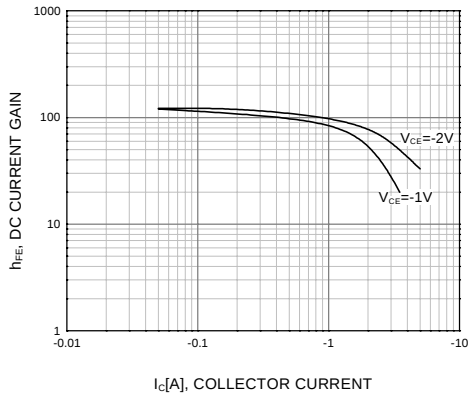


Figure 1. DC current Gain

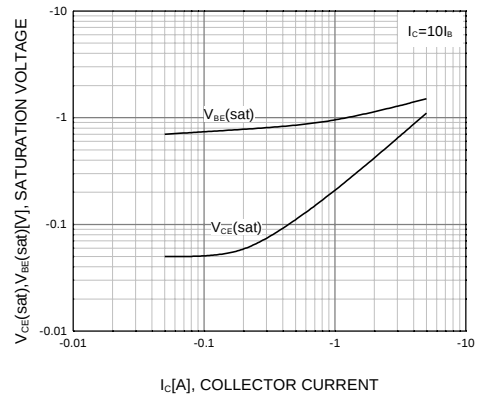


Figure 2. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

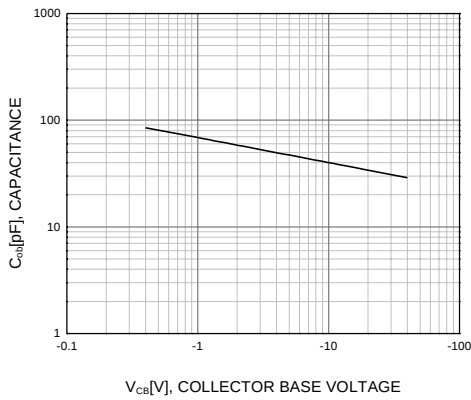


Figure 3. Collector Output Capacitance

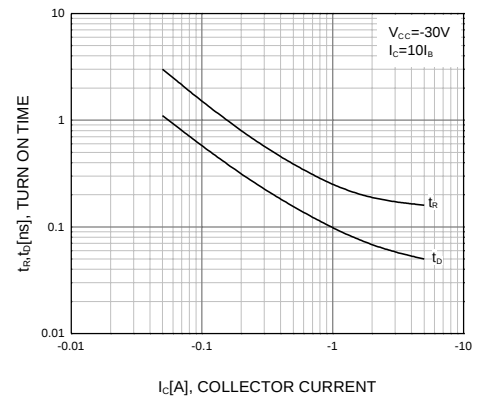


Figure 4. Turn On Time

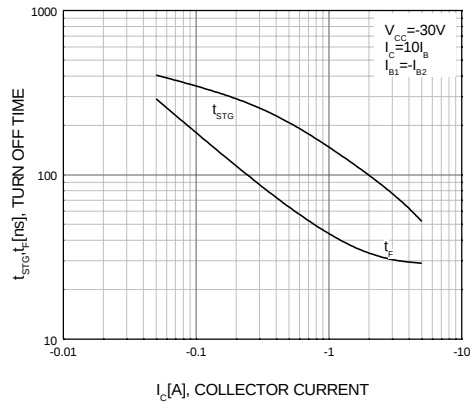


Figure 5. Turn Off Time

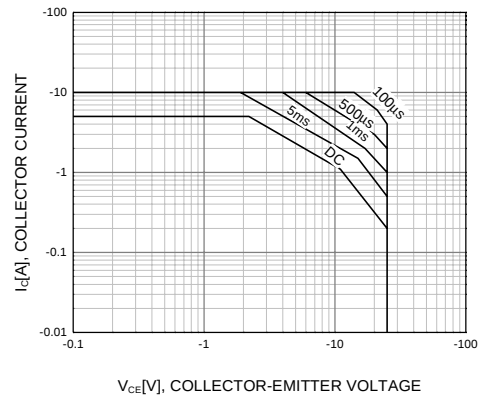


Figure 6. Safe Operating Area

Typical Characteristics (Continued)

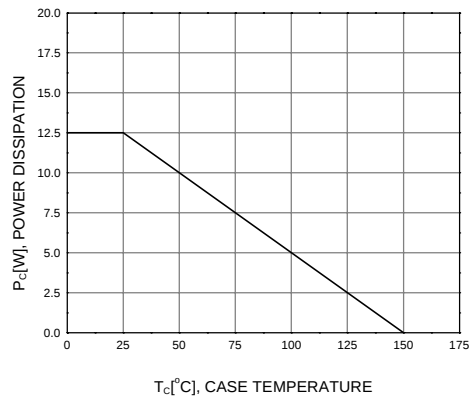
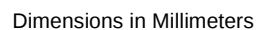


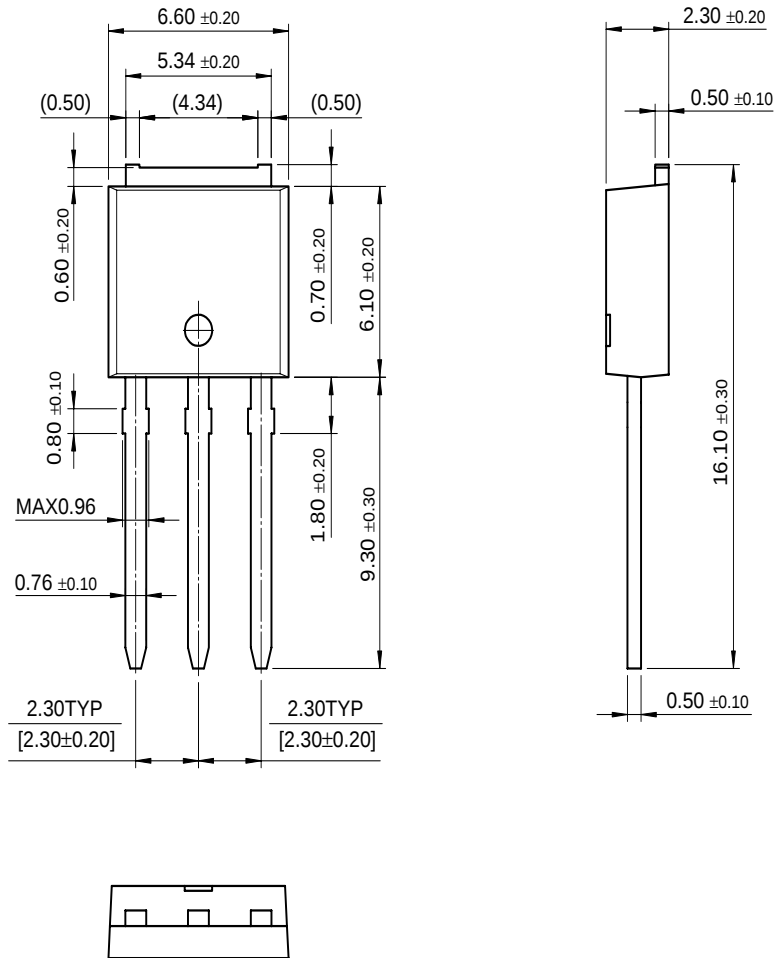
Figure 7. Power Derating

D-PAK



Package Dimensions (Continued)

I-PAK



Dimensions in Millimeters

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